



AP62250

#### 4.2V TO 18V INPUT, 2.5A LOW IQ SYNCHRONOUS BUCK CONVERTER

### **Description**

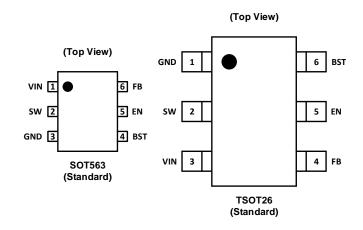
The AP62250 is a 2.5A, synchronous buck converter with a wide input voltage range of 4.2V to 18V. The device fully integrates a  $75m\Omega$  high-side power MOSFET and a  $45m\Omega$  low-side power MOSFET to provide high-efficiency step-down DC-DC conversion.

The AP62250 device is easily used by minimizing the external component count due to its adoption of Constant On-Time (COT) control to achieve fast transient response, easy loop stabilization, and low output voltage ripple.

The AP62250 design is optimized for Electromagnetic Interference (EMI) reduction. The device has a proprietary gate driver scheme to resist switching node ringing without sacrificing MOSFET turn-on and turn-off times, which reduces high-frequency radiated EMI noise caused by MOSFET switching.

AP62250 is available in SOT563 (Standard) and TSOT26 (Standard) packages.

## **Pin Assignments**



#### **Features**

- VIN: 4.2V to 18V
- Output Voltage (VOUT): 0.8V to 7V
- 2.5A Continuous Output Current
- 0.8V ± 1% Reference Voltage (T<sub>A</sub> = +25°C)
- 155µA Low Quiescent Current (Pulse Frequency Modulation)
- 1.3MHz Switching Frequency (VIN = 12V, VOUT = 5V)
- Proprietary Gate Driver Design for Best EMI Reduction
- Protection Circuitry
  - Undervoltage Lockout (UVLO)
  - Cycle-by-Cycle Valley Current Limit
  - Thermal Shutdown
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

## **Applications**

- 5V and 12V Distributed Power Bus Supplies
- Flat Screen TV Sets and Monitors
- White Goods and Small Home Appliances
- FPGA, DSP, and ASIC Supplies
- Home Audio
- Network Systems
- Gaming Consoles
- Consumer Electronics
- General Purpose Point of Load

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



## **Typical Application Circuit**

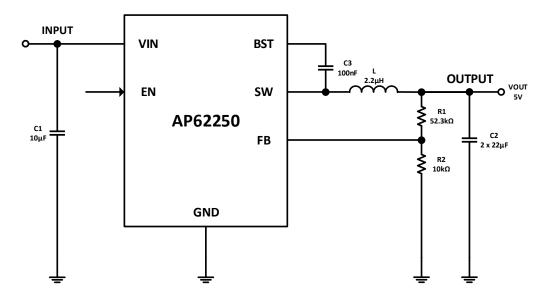


Figure 1. Typical Application Circuit

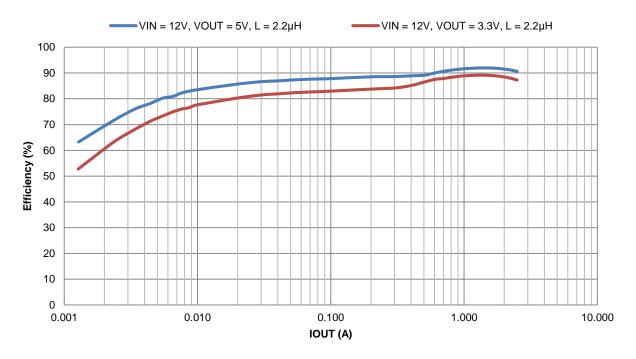


Figure 2. Efficiency vs. Output Current



## **Pin Descriptions**

Pin	Pin No	umber	
Name	SOT563	TSOT26	Function
Name	(Standard) (Standa		
			Power Input. VIN supplies the power to the IC as well as the step-down converter power MOSFETs. Drive VIN
VIN	1	3	with a 4.2V to 18V power source. Bypass VIN to GND with a suitably large capacitor to eliminate noise due to
			the switching of the IC. See Input Capacitor section for more details.
SW	2	2	Power Switching Output. SW is the switching node that supplies power to the output. Connect the output LC
SVV	SVV   2   2		filter from SW to the output load.
GND	3	1	Power Ground.
BST	4	6	High-Side Gate Drive Boost Input. BST supplies the drive for the high-side N-Channel MOSFET. A 100nF
D31	4	O	capacitor is recommended from BST to SW to power the high-side driver.
			Enable Input. EN is a digital input that turns the regulator on or off. Drive EN high to turn on the regulator and
EN	5	5	low to turn it off. Leave floating for automatic startup. The EN has a precision threshold of 1.2V for programing
			the UVLO. See <b>Enable</b> section for more details.
FB	6	4	Feedback sensing terminal for the output voltage. Connect this pin to the resistive divider of the output. See
1.0	Ö	7	Setting the Output Voltage section for more details.

## **Functional Block Diagram**

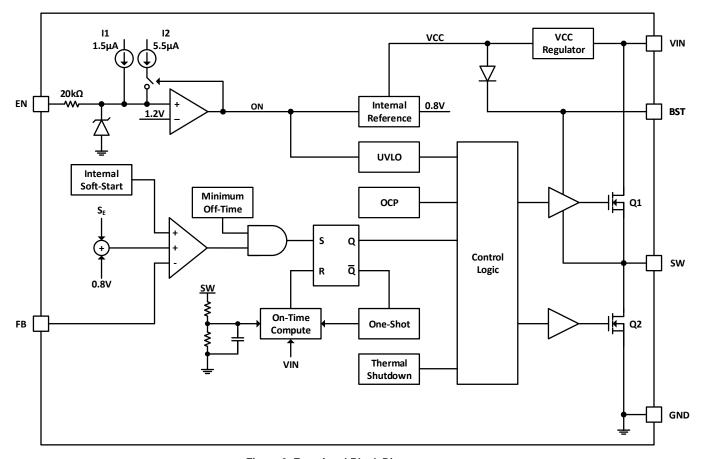


Figure 3. Functional Block Diagram



## Absolute Maximum Ratings (Note 4) (@ TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
VIN	Supply Pin Voltage	-0.3 to +20.0 (DC)	V	
VIIN	Supply Fill Voltage	-0.3 to +22.0 (400ms)	7 <b>v</b>	
Vsw	Switch Pin Voltage	-1.0 to VIN + 0.3 (DC)	V	
VSW	Switch Fill Voltage	-2.5 to VIN + 2.0 (20ns)	<b>7</b>	
V <sub>BST</sub>	Bootstrap Pin Voltage	V <sub>SW</sub> - 0.3 to V <sub>SW</sub> + 6.0	V	
V <sub>EN</sub>	Enable/UVLO Pin Voltage	-0.3 to +6.0	V	
V <sub>FB</sub>	Feedback Pin Voltage	-0.3 to +6.0	V	
Tst	Storage Temperature	-65 to +150	°C	
TJ	Junction Temperature	+160	°C	
TL	Lead Temperature	+260	°C	
ESD Susceptibility	(Note 5)	•	•	
HBM	Human Body Model	±2000	V	
CDM	Charged Device Model	±500	V	

Notes:

- 4. Stresses greater than the *Absolute Maximum Ratings* specified above can cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability can be affected by exposure to absolute maximum rating conditions for extended periods of time.
- 5. Semiconductor devices are ESD sensitive and can be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.

### Thermal Resistance (Note 6)

Symbol	Parameter	Rati	ing	Unit
θја	Junction to Ambient	SOT563 (Standard)	110	°C/W
OJA		TSOT26 (Standard)	70	
0	IJunction to Case	SOT563 (Standard)	8	°C/W
θјС		TSOT26 (Standard)	12	

Note:

## Recommended Operating Conditions (Note 7) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
VIN	Supply Voltage	4.2	18.0	V
VOUT	Output Voltage	0.8	7.0	V
TA	Operating Ambient Temperature	-40	+85	°C
TJ	Operating Junction Temperature	-40	+125	°C

Note: 7. The device function is not guaranteed outside of the recommended operating conditions.

<sup>6.</sup> Test condition for SOT563 (Standard)/TSOT26 (Standard): Device mounted on FR-4 substrate, two-layer PCB, 2oz copper, with minimum recommended pad layout.

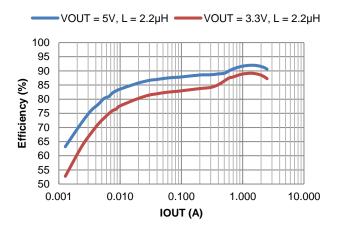


**Electrical Characteristics** (@  $T_J = +25^{\circ}C$ , VIN = 12V, unless otherwise specified. Min/Max limits apply across the recommended operating junction temperature range, -40°C to +125°C, and input voltage range, 4.2V to 18V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Ishdn	Shutdown Supply Current	VEN = 0V	_	1.5	_	μA
Iq	Quiescent Supply Current	V <sub>FB</sub> = 0.85V	_	155	_	μA
POR	VIN Power-on Reset Rising Threshold	_	_	3.90	4.15	V
UVLO	VIN Undervoltage Lockout Falling Threshold	_	_	3.6	_	V
RDS(ON)1	High-Side Power MOSFET On-Resistance (Note 8)	_	_	75	_	mΩ
RDS(ON)2	Low-Side Power MOSFET On-Resistance (Note 8)	_	_	45	_	mΩ
IVALLEY_LIMIT	LS Valley Current Limit (Note 8)	From source to drain	3.2	3.7	4.2	Α
fsw	Oscillator Frequency	VOUT = 5V, CCM	_	1.3	_	MHz
t <sub>ON_MIN</sub>	Minimum On-Time	_	_	65	_	ns
toff_min	Minimum Off-Time	_	_	200	_	ns
VFB	Feedback Voltage	$T_A = +25$ °C, CCM	0.792	0.800	0.808	V
VFB		CCM	0.784	0.800	0.816	V
VEN_H	EN Logic High Threshold	_	_	1.20	1.25	V
V <sub>EN_L</sub>	EN Logic Low Threshold	_	1.04	1.10	_	V
1	EN land Owner	V <sub>EN</sub> = 1.5V	_	7.0	_	μA
IEN	EN Input Current	V <sub>EN</sub> = 1V	1.0	1.5	2.0	μA
tss	Soft-Start Time	_	_	2.5	_	ms
T <sub>SD</sub>	Thermal Shutdown (Note 8)	_	_	+160	_	°C
T <sub>Hys</sub>	Thermal Shutdown Hysteresis (Note 8)	_	_	+20	_	°C

Note: 8. Compliance to the datasheet limits is assured by one or more methods: production test, characterization, and/or design.





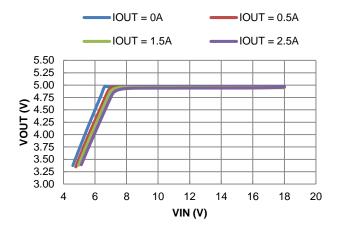


Figure 4. Efficiency vs. Output Current, VIN = 12V

Figure 5. Line Regulation

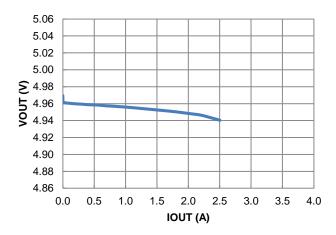


Figure 6. Load Regulation



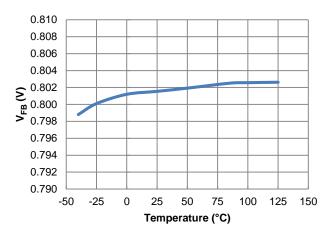


Figure 7. Feedback Voltage vs. Temperature

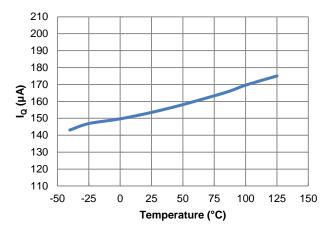


Figure 9. IQ vs. Temperature

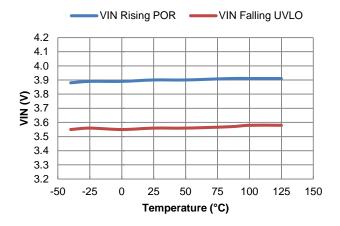


Figure 11. VIN Power-On Reset and UVLO vs. Temperature

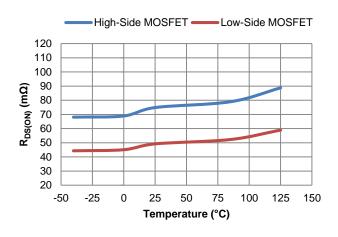


Figure 8. Power MOSFET RDS(ON) vs. Temperature

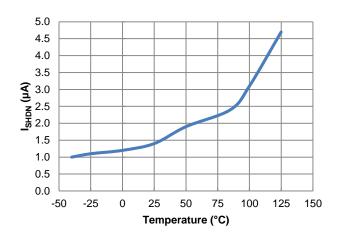


Figure 10. Ishon vs. Temperature

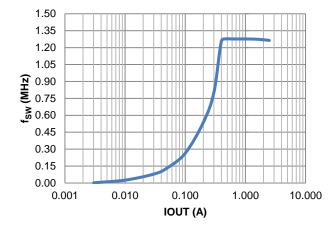


Figure 12. fsw vs. Load



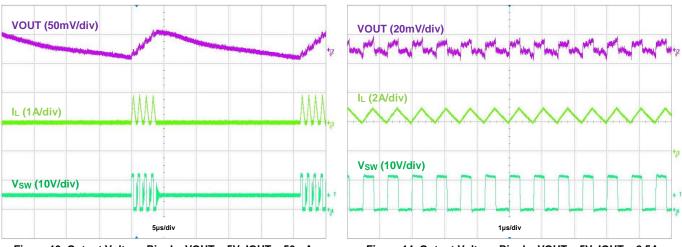


Figure 13. Output Voltage Ripple, VOUT = 5V, IOUT = 50mA

Figure 14. Output Voltage Ripple, VOUT = 5V, IOUT = 2.5A

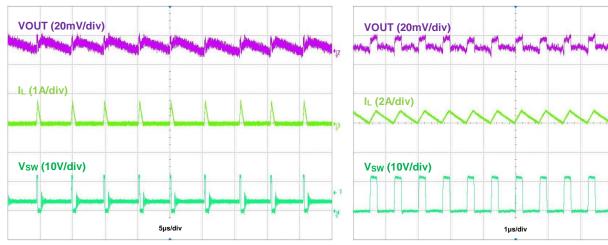


Figure 15. Output Voltage Ripple, VOUT = 3.3V, IOUT = 50mA

Figure 16. Output Voltage Ripple, VOUT = 3.3V, IOUT = 2.5A



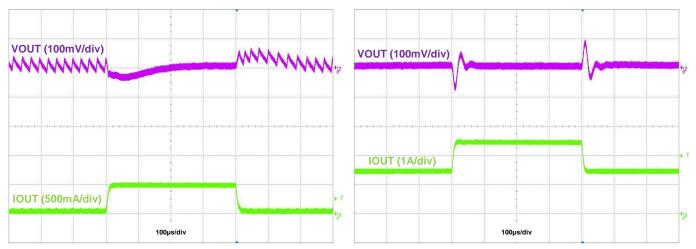


Figure 17. Load Transient, IOUT = 50mA to 500mA to 50mA

Figure 18. Load Transient, IOUT = 1.5A to 2.5A to 1.5A

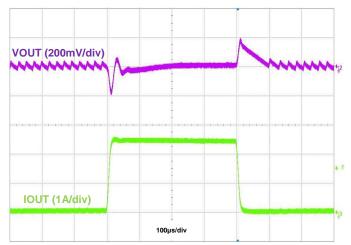


Figure 19. Load Transient, IOUT = 50mA to 2.5A to 50mA



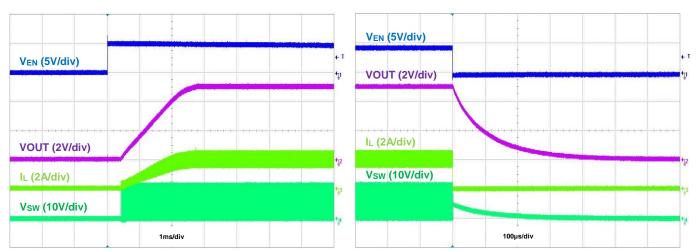


Figure 20. Startup Using EN, IOUT = 2.5A

Figure 21. Shutdown Using EN, IOUT = 2.5A

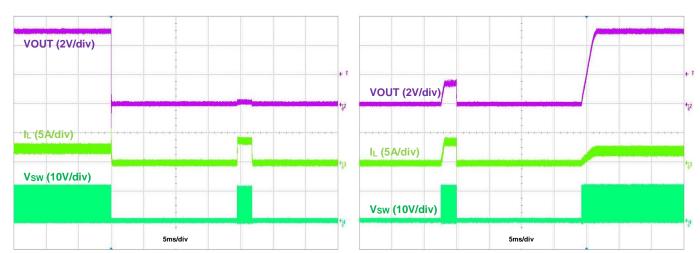


Figure 22. Output Short Protection, IOUT = 2.5A

Figure 23. Output Short Recovery, IOUT = 2.5A



## **Application Information**

#### 1 Pulse Width Modulation (PWM) Operation

The AP62250 device is a 4.2V-to-18V input, 2.5A output, EMI friendly, fully integrated synchronous buck converter. Refer to the block diagram in Figure 3. The device employs constant on-time control to provide fast transient response and easy loop stabilization. At the beginning of each cycle, the one-shot pulse turns on the high-side power MOSFET, Q1, for a fixed on-time, toN. This one-shot on-pulse timing is calculated by the converter's input voltage and output voltage to maintain a pseudo-fixed frequency over the input voltage range. When Q1 is on, the inductor current rises linearly and the device charges the output capacitor. Q1 turns off after the fixed on-time expires, and the low-side power MOSFET, Q2, turns on. Once the output voltage drops below the output regulation, Q2 turns off. The one-shot timer is then reset and Q1 turns on again. The on-time is inversely proportional to the input voltage and directly proportional to the output voltage. It is calculated by the following equation:

$$\mathbf{t_{ON}} = \frac{\mathbf{VOUT}}{\mathbf{VIN} \cdot \mathbf{f_{SW}}}$$
 Eq. 1

Where:

- VIN is the input voltage
- VOUT is the output voltage
- f<sub>SW</sub> is the switching frequency

The off-time duration is tope and starts after the on-time expires. The off-time expires when the feedback voltage decreases below the reference voltage, which then triggers the on-time duration to start again. The minimum off-time is 200ns typical.

#### 2 Pulse Frequency Modulation (PFM) Operation

The AP62250 enters PFM operation at light load conditions for high efficiency. During light load conditions, the regulator automatically reduces the switching frequency. As the output current decreases, so too does the inductor current. The inductor current, I<sub>L</sub>, eventually reaches 0A, marking the boundary between Continuous Conduction Mode (CCM) and Discontinuous Condition Mode (DCM). During this time, both Q1 and Q2 are off, and the load current is provided only by the output capacitor. When V<sub>FB</sub> becomes lower than 0.8V, the next cycle begins, and Q1 turns on.

Likewise, as the output load increases from light load to heavy load, the switching frequency increases to maintain the regulation of the output voltage. The transition point between light and heavy load conditions can be calculated using the following equation:

$$I_{LOAD} = \left( \frac{VIN - VOUT}{2L} \right) \cdot t_{ON} \tag{Eq. 2}$$

Where:

• L is the inductor value

The quiescent current of AP62250 is 155µA typical under a no-load, non-switching condition.

#### 3 Enable

When disabled, the device shutdown supply current is only 1.5µA. When applying a voltage greater than the EN logic high threshold (typical 1.2V, rising), the AP62250 enables all functions and the device initiates the soft-start phase. An internal 1.5µA pull-up current source connected from the internal LDO-regulated VCC to the EN pin guarantees that if EN is left floating, the device still automatically enables once the voltage reaches the EN logic high threshold. The AP62250 has a built-in 2.5ms soft-start time to prevent output voltage overshoot and inrush current. When the EN voltage falls below its logic low threshold (typical 1.1V, falling), the internal SS voltage discharges to ground and device operation disables.

The EN pin can also be used to program the undervoltage lockout thresholds. See Undervoltage Lockout (UVLO) section for more details.



#### 3 Enable (continued)

Alternatively, a small ceramic capacitor can be added from EN to GND. When EN is not driven externally, this capacitor increases the time needed for the EN pin voltage to reach its logic high threshold, which delays the startup of the output voltage. This is useful when sequencing multiple power rails to minimize input inrush current. When the EN pin voltage starts from 0V, the amount of capacitance for a given delay time is approximated by:

$$C_d[nF] \approx 0.278 \cdot t_d[ms]$$
 Eq. 3

#### Where:

- C<sub>d</sub> is the time delay capacitance in nF
- td is the delay time in ms

#### 4 Electromagnetic Interference (EMI) Reduction with Ringing-Free Switching Node

In some applications, the system must meet EMI standards. In relation to high frequency radiation EMI noise, the switching node's (SW's) ringing amplitude is especially critical. To dampen high frequency radiated EMI noise, the AP62250 device implements a proprietary, multi-level gate driver scheme that achieves a ringing-free switching node without sacrificing the switching node's rise and fall slew rates as well as the converter's power efficiency.

#### 5 Adjusting Undervoltage Lockout (UVLO)

Undervoltage lockout is implemented to prevent the IC from insufficient input voltages. The AP62250 device has a UVLO comparator that monitors the input voltage and the internal bandgap reference. The AP62250 disables if the input voltage falls below 3.6V. In this UVLO event, both the high-side and low-side power MOSFETs turn off.

Some applications may desire higher VIN UVLO threshold voltages than is provided by the default setup. A 5.5µA hysteresis pull-up current source on the EN pin along with an external resistive divider (R3 and R4) configures the VIN UVLO threshold voltages as shown in Figure 24.

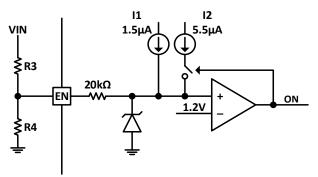


Figure 24. Programming UVLO

The resistive divider resistor values are calculated by:

$$R3 = \frac{0.917 \cdot V_{ON} - V_{OFF}}{5.625 \mu A}$$
 Eq. 4

$$R4 = \frac{1.\,1\cdot R3}{V_{OFF} - 1.\,1V + 7\mu A\cdot R3} \label{eq:R4}$$
 Eq. 5

#### Where:

- Von is the rising edge VIN voltage to enable the regulator and is greater than 4.15V
- V<sub>OFF</sub> is the falling edge VIN voltage to disable the regulator and is greater than 3.85V



### 6 Overcurrent Protection (OCP)

The AP62250 has cycle-by-cycle valley current limit protection by sensing the current through the internal low-side power MOSFET, Q2. While Q2 is on, the internal sensing circuitry monitors its conduction current. The overcurrent limit has a corresponding voltage limit, V<sub>LIMIT</sub>. When the voltage between GND and SW is lower than V<sub>LIMIT</sub> due to excessive current through Q2, the OCP triggers, and the controller turns off Q2. During this time, both Q1 and Q2 remain off. A new switching cycle begins only when the voltage between GND and SW rises above V<sub>LIMIT</sub>. If Q2 consistently hits the valley current limit for 2.5ms, the buck converter enters hiccup mode and shuts down. After 20ms of down time, the buck converter restarts powering up. Hiccup mode reduces the power dissipation in the overcurrent condition.

Because the R<sub>DS(ON)</sub> values of the power MOSFETs increase with temperature, V<sub>LIMIT</sub> has a temperature coefficient of 0.4%/°C to compensate for the temperature dependency of R<sub>DS(ON)</sub>.

#### 7 Thermal Shutdown (TSD)

If the junction temperature of the device reaches the thermal shutdown limit of +160°C, the AP62250 shuts down both its high-side and low-side power MOSFETs. When the junction temperature reduces to the required level (+140°C typical), the device initiates a normal power-up cycle with soft-start.

#### 8 Power Derating Characteristics

To prevent the regulator from exceeding the maximum recommended operating junction temperature, some thermal analysis is required. The regulator's temperature rise is given by:

$$T_{RISE} = PD \cdot (\theta_{IA})$$
 Eq. 6

Where:

- PD is the power dissipated by the regulator
- θ<sub>JA</sub> is the thermal resistance from the junction of the die to the ambient temperature

The junction temperature,  $T_J$ , is given by:

$$T_{J} = T_{A} + T_{RISE}$$
 Eq. 7

Where:

• TA is the ambient temperature of the environment



### 8 Power Derating Characteristics (continued)

For the SOT563 (Standard) and TSOT26 (Standard) packages, the  $\theta_{JA}$  is 110°C/W and 70°C/W, respectively. The actual junction temperature should not exceed the maximum recommended operating junction temperature of +125°C when considering the thermal design. Figure 25 and Figure 26 show typical derating curves versus ambient temperature.

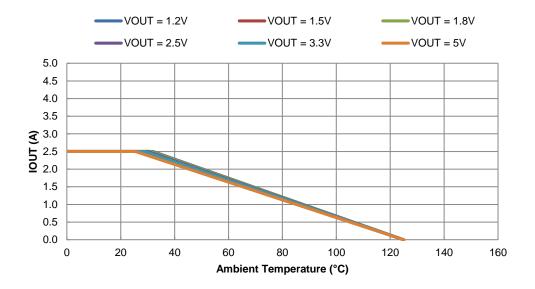


Figure 25. Output Current Derating Curve vs. Ambient Temperature, SOT563 (Standard) Package, VIN = 12V

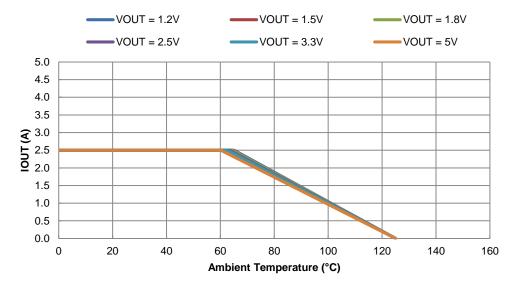


Figure 26. Output Current Derating Curve vs. Ambient Temperature, TSOT26 (Standard) Package, VIN = 12V



#### 9 Setting the Output Voltage

The AP62250 has adjustable output voltages, starting from 0.8V, using an external resistive divider. The resistor values of the feedback network are selected based on a design trade-off between efficiency and output voltage accuracy. There is less current consumption in the feedback network for high resistor values, which improves efficiency at light loads. However, values too high cause the device to be more susceptible to noise affecting its output voltage accuracy. R1 can be determined by the following equation:

$$R1 = R2 \cdot \left(\frac{VOUT}{0.8V} - 1\right)$$
 Eq. 8

Table 1 shows a list of recommended component selections for common AP62250 output voltages referencing Figure 1. Consult Diodes Incorporated for other output voltage requirements.

AP62250 Output Voltage (V) R1 (kΩ) R2 (kΩ) L (µH) C1 (µF) C2 (µF) C3 (nF) 1.2 4.99 10 1.0 10 2 x 22 100 1.5 8.66 10 1.0 10 2 x 22 100 1.8 12.4 10 1.5 10 2 x 22 100 2.5 21.5 10 1.5 10 2 x 22 100 3.3 31.6 10 2.2 10 100 2 x 22 5.0 52.3 10 2.2 10 2 x 22 100

**Table 1. Recommended Component Selections** 

#### 10 Inductor

Calculating the inductor value is a critical factor in designing a buck converter. For most designs, the following equation can be used to calculate the inductor value:

$$L = \frac{VOUT \cdot (VIN - VOUT)}{VIN \cdot \Delta I_L \cdot f_{SW}}$$
 Eq. 9

#### Where:

- ΔI<sub>L</sub> is the inductor current ripple
- fsw is the buck converter switching frequency

For AP62250, choose  $\Delta I_L$  to be 30% to 50% of the maximum load current of 2.5A.

The inductor peak current is calculated by:

$$I_{L_{PEAK}} = I_{LOAD} + \frac{\Delta I_{L}}{2}$$
 Eq. 10

Peak current determines the required saturation current rating, which influences the size of the inductor. Saturating the inductor decreases the converter efficiency while increasing the temperatures of the inductor and the internal power MOSFETs. Therefore, choosing an inductor with the appropriate saturation current rating is important. For most applications, it is recommended to select an inductor of approximately  $1.0\mu H$  to  $2.2\mu H$  with a DC current rating of at least 35% higher than the maximum load current. For highest efficiency, the inductor's DC resistance should be less than  $30m\Omega$ . Use a larger inductance for improved efficiency under light load conditions.



#### 11 Input Capacitor

The input capacitor reduces both the surge current drawn from the input supply as well as the switching noise from the device. The input capacitor must sustain the ripple current produced during the on-time of Q1. It must have a low ESR to minimize power dissipation due to the RMS input current.

The RMS current rating of the input capacitor is a critical parameter and must be higher than the RMS input current. As a rule of thumb, select an input capacitor with an RMS current rating greater than half of the maximum load current.

Due to large dl/dt through the input capacitor, electrolytic or ceramic capacitors with low ESR should be used. If using a tantalum capacitor, it must be surge protected or else capacitor failure could occur. Using a ceramic capacitor of 10µF or greater is sufficient for most applications.

#### 12 Output Capacitor

The output capacitor keeps the output voltage ripple small, ensures feedback loop stability, and reduces both the overshoots and undershoots of the output voltage during load transients. During the first few microseconds of an increasing load transient, the converter recognizes the change from steady-state and sets the off-time to minimum to supply more current to the load. However, the inductor limits the change to increasing current depending on its inductance. Therefore, the output capacitor supplies the difference in current to the load during this time. Likewise, during the first few microseconds of a decreasing load transient, the converter recognizes the change from steady-state and increases the off-time to reduce the current supplied to the load. However, the inductor limits the change in decreasing current as well. Therefore, the output capacitor absorbs the excess current from the inductor during this time.

The effective output capacitance, COUT, requirements can be calculated from the equations below.

The ESR of the output capacitor dominates the output voltage ripple. The amount of ripple can be calculated by:

$$VOUT_{Ripple} = \Delta I_{L} \cdot \left(ESR + \frac{1}{8 \cdot f_{sw} \cdot COUT}\right)$$
 Eq. 11

An output capacitor with large capacitance and low ESR is the best option. For most applications, a 22µF to 68µF ceramic capacitor is sufficient. To meet the load transient requirements, the calculated COUT should satisfy the following inequality:

$$COUT > max \left( \frac{L \cdot I_{Trans}^2}{\Delta V_{Overshoot} \cdot VOUT}, \frac{L \cdot I_{Trans}^2}{\Delta V_{Undershoot} \cdot (VIN - VOUT)} \right)$$
 Eq. 12

#### Where:

- ITrans is the load transient
- ΔV<sub>Overshoot</sub> is the maximum output overshoot voltage
- ΔV<sub>Undershoot</sub> is the maximum output undershoot voltage

#### 13 Bootstrap Capacitor

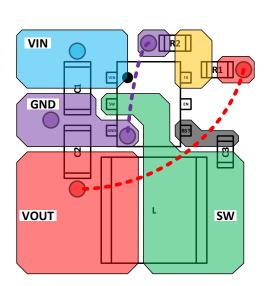
To ensure proper operation, a ceramic capacitor must be connected between the BST and SW pins to supply the drive voltage for the high-side power MOSFET. A 100nF ceramic capacitor is sufficient.



### Layout

#### **PCB** Layout

- 1. The AP62250 works at 2.5A load current so heat dissipation is a major concern in the layout of the PCB. 2oz copper for both the top and bottom layers is recommended.
- 2. Place the input capacitors as closely across VIN and GND as possible.
- 3. Place the inductor as close to SW as possible.
- 4. Place the output capacitors as close to GND as possible.
- 5. Place the feedback components as close to FB as possible.
- 6. If using four or more layers, use at least the 2<sup>nd</sup> and 3<sup>rd</sup> layers as GND to maximize thermal performance.
- 7. Add as many vias as possible around both the GND pin and under the GND plane for heat dissipation to all the GND layers.
- 8. Add as many vias as possible around both the VIN pin and under the VIN plane for heat dissipation to all the VIN layers.
- 9. See Figure 27 and Figure 28 for more details.



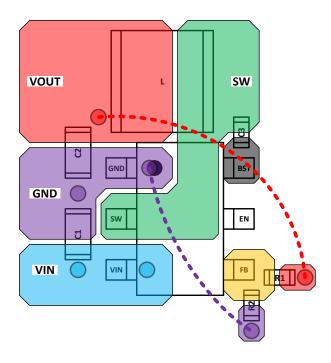
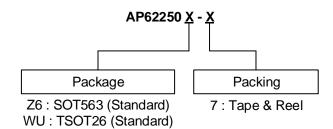


Figure 27. Recommended PCB Layout, SOT563 (Standard)

Figure 28. Recommended PCB Layout, TSOT26 (Standard)



## **Ordering Information**



Part Number	Package Code	Tape and Reel		
Fait Number	Fackage Code	Quantity	Part Number Suffix	
AP62250Z6-7	Z6	3000	-7	
AP62250WU-7	WU	3000	-7	

## **Marking Information**

#### SOT563 (Standard)/TSOT26 (Standard)

## (Top View)

6 5 XX Y W X 2 3

XX: Identification Code

<u>Y</u> : Year 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

X: Internal Code

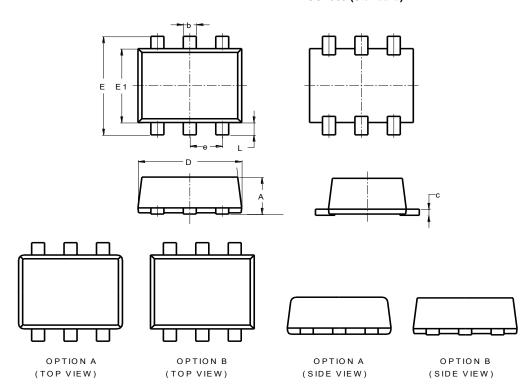
Part Number	Package	Identification Code
AP62250Z6-7	SOT563 (Standard)	HG
AP62250WU-7	TSOT26 (Standard)	HH



## **Package Outline Dimensions**

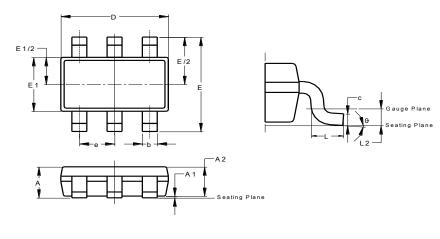
 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$ 

#### SOT563 (Standard)

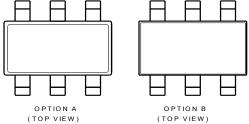


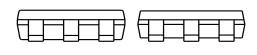
SOT563 (Standard)					
Dim	Min	Max	Тур		
Α	0.53	0.60			
b	0.15	0.30	0.20		
С	0.10	0.18	0.11		
D	1.50         1.70         1.6           1.50         1.70         1.6				
Е					
E1	1.10	1.30	1.20		
е	0.50 BSC				
L	0.10	0.30	0.20		
All Dimensions in mm					

#### TSOT26 (Standard)



TS	TSOT26 (Standard)				
Dim	Min	Max	Тур		
Α		1.00			
A1	0.00	0.10			
A2	0.75	0.90	0.80		
D	2.70	3.10	2.90		
Е	2.60 3.00 2.8				
E1	1.50	1.50 1.70			
b	0.30 0.50 0.4		0.44		
С	0.11	0.20	0.16		
е	(	).95 BSC	)		
L	0.30	0.50	0.40		
L2	0.25 BSC				
θ	0° 8° 4°				
All	All Dimensions in mm				





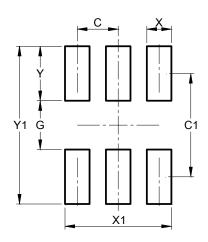
OPTION A (SIDE VIEW) OPTION B (SIDE VIEW)



## **Suggested Pad Layout**

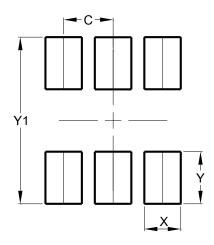
Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT563 (Standard)



Dimensions	Value (in mm)
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Υ	0.670
Y1	1.940

#### TSOT26 (Standard)



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
V1	3 200

## **Mechanical Data**

### SOT563 (Standard)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.003 grams (Approximate)

#### TSOT26 (Standard)

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.013 grams (Approximate)



#### **IMPORTANT NOTICE**

- 1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- 2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- 3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
- 4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- 5. Diodes products are provided subject to Diodes' Standard Terms and Conditions of Sale (<a href="https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/">https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/</a>) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- 7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- 8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated:

AP62250WU-7 AP62250Z6-7